Not Recommended For New Designs



ancasar Stanner

DAC8581

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16-BIT, HIGH-SPEED, LOW-NOISE, VOLTAGE OUTPUT DIGITAL-TO-ANALOG CONVERTER

Check for Samples: DAC8581

FEATURES

- 16-Bit Monotonic
- ±5-V Bipolar Output
- Very Low Glitch: 0.5 nV-s
- Fast Settling: 0.65 µs
- Fast Slew Rate: 35 V/µs
- Low Noise: 20 nV/ \sqrt{Hz}
- ±25-mA Load Drive
- ±5-V Dual Power Supply
- Single External Reference
- Power-On Reset to Midscale
- 3-MSPS Update Rate
- SPI[™] Interface, Up to 50 MHz
- 1.8-V-5-V Logic Compatible
- Twos Complement Data Format
- Hardware Reset to Midscale
- TSSOP-16 Package

APPLICATIONS

- Industrial Process Control
- CRT Projection TV Digital Convergence
- Waveform Generation
- Automated Test Equipment
- Ultrasound

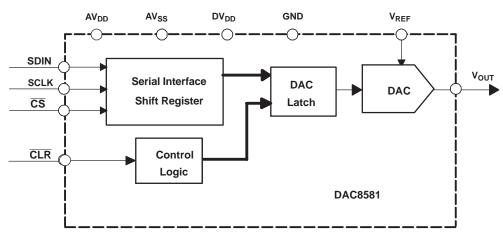
DESCRIPTION

The DAC8581 is a 16-bit, high-speed, low-noise DAC operating from dual \pm 5-V power supplies. The DAC8581 is monotonic, and has exceptionally low noise and exceptionally low glitch. The DAC8581 high-performance, bipolar output buffer is capable of settling within 0.65 µs for a 10-V step. Small-signal settling time is well under 0.3 µs, supporting data update rates up to 3 MSPS. A power-on-reset circuit sets the output at midscale voltage on power up.

The DAC8581 is simple to use, with a single external reference and a standard 3-wire SPI interface that allows clock rates up to 50 MHz.

Also see the DAC8580, a member of the same family. The DAC8580 combines DAC8581 performance with an on-chip, 16x over-sampling digital filter.

The DAC8581 is specified over the -40° C to $+85^{\circ}$ C temperature range.



FUNCTIONAL BLOCK DIAGRAM OF DAC8581

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DAC8581



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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

PACKAGE/ORDERING INFORMATION ⁽¹⁾								
PRODUCT	PACKAGE	PACKAGE DRAWING NUMBER	SPECIFICATION TEMPERATURE RANGE	PACKAGE ORDERING MARKING	ORDERING NUMBER	TRANSPORT MEDIA, QUANTITY		
DAC8581	TSSOP-16		4000 10 00500	Docodi	DAC8581IPW	Tube, 90-Piece		
DAC8581	1330P-16	PW	–40°C to +85°C	D8581I	DAC8581IPWR	Tape and Reel, 2000-Piece		

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

		UNIT
$\rm AV_{\rm DD}$ or $\rm DV_{\rm DD}$ to $\rm AV_{\rm SS}$		-0.3 V to 12 V
Digital input voltage to AV_{SS}		-0.3 V to 12 V
V_{OUT} or V_{REF} to AV_{SS}		-0.3 V to 12 V
DGND and AGND to AV _{SS}		–0.3 V to 6 V
Operating temperature range		–40°C to +85°C
Storage temperature range		-65°C to +150°C
Junction temperature range (T	J max)	+150°C
Dower dissipation	Thermal impedance (θ _{JA})	118°C/W
Power dissipation	Thermal impedance (θ _{JC})	29°C/W

(1) Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum conditions for extended periods may affect device reliability.



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ELECTRICAL CHARACTERISTICS

All specifications at $T_A = T_{MIN}$ to T_{MAX} , +AV_{DD} = +5 V, -AV_{DD} = -5 V, DV_{DD} = +5 V (unless otherwise noted).

			DAC8581			
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
STATIC PERFORMANCE				,		
Resolution		16			Bits	
Linearity error	V _{REF} = 4.096 V		±0.03	±0.1	%FS	
Differential linearity error			±0.25	±0.5	LSB	
Gain error		1	2	3	%FS	
Gain drift			±5		ppm/°C	
Bipolar zero error			-5	±25	mV	
Bipolar zero drift			±20		µV/°C	
Total drift			±10		ppm/°C	
OUTPUT CHARACTERISTICS						
Voltage output	V_{REF} up to 5.5 V, when AV_{DD} = 6 V, AV_{SS} = –6 V	–V _{REF}		V _{REF}	V	
Output impedance			1		Ω	
Maximum output current			±25		mA	
	C_L < 200 pF, R_L = 2 k Ω , to 0.1% FS, 8-V step		0.65			
Settling time	To 0.003% FS		1		μs	
Slew rate ⁽¹⁾			35		V/µs	
Code change glitch	1 LSB change around major carry		0.5		nV-S	
Overshoot	Full-scale change		50		mV	
Digital feedthrough ⁽²⁾			0.5		nV-S	
SNR	Digital sine wave input, f _{OUT} = 1 kHz, BW = 10 kHz, 2-MSPS update rate		108		dB	
THD	Digital sine wave input, f _{OUT} = 20 kHz, 8-V _{PP} output, 2-MSPS update rate		-72		dB	
	0.1 Hz to 10 Hz		25		μV_{PP}	
Output voltage noise	At 10-kHz offset frequency		25		nV/√Hz	
	At 100-kHz offset frequency		20		nV/√Hz	
Power supply rejection	VDD varies ±10%		0.75		mV/V	
REFERENCE				<u> </u>		
	Large signal: 2-V _{PP} sine wave on 4 V DC		3		MHz	
Reference input bandwidth	Small signal: 100-mV _{PP} sine wave on 4 V DC		10		MHz	
Reference input voltage range		3		AV _{DD}	V	
Reference input impedance			5		kΩ	
Reference input capacitance			5		pF	
DIGITAL INPUTS	· · · · · · · · · · · · · · · · · · ·					
V _{IH}				0.7 x DV_{DD}	.,	
V _{IL}		GND		0.3 x DV _{DD}	V	
Input current				±1	μA	
Input capacitance				10	pF	
Power-on delay	From V_{DD} high to \overline{CS} low		20		μs	

(1) Slew rate is measured from 10% to 90% of transition when the output changes from 0 to full-scale.

(2) Digital feedthrough is defined as the impulse injected into the analog output from the digital input. It is measured when the DAC output does not change, CS is held high, and while SCLK and SDIN signals are toggled.



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ELECTRICAL CHARACTERISTICS (continued)

All specifications at $T_A = T_{MIN}$ to T_{MAX} , +AV_{DD} = +5 V, -AV_{DD} = -5 V, DV_{DD} = +5 V (unless otherwise noted).

			DAC8581		
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
POWER SUPPLY			,	,	
+AV _{DD}		4.0	5	6.0	V
-AV _{DD}		-4.0	-5	-6.0	V
DV _{DD}		1.8		AV_{DD}	V
I _{DVDD}			10	20	μA
I _{DD}	I_{REF} and IDV _{DD} included		17	24	mA
I _{SS}			-23	-32	mA
TEMPERATURE RANGE		·			
Specified performance		-40		+85	°C

PIN CONFIGURATION

PW PACKAGE TSSOP-16 (TOP VIEW)

	(101 112	,	
V _{REF}	10	16	
V _{OUT} 🗖	2	15	
AV _{SS}	3	14	
AV _{DD}	4	13	
AGND 🗖	5	12	
DGND 🗖	6	11	
DGND	7	10	III SCLK
DGND 🗖	8	9	D SDIN

TERMINAL FUNCTIONS

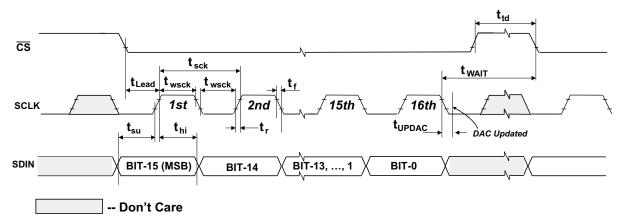
TERMINAL		
NAME	NO.	
V _{REF}	1	Reference input voltage.
VOUT	2	DAC output voltage. Output swing is ±V _{REF}
AV _{SS}	3	Negative analog supply voltage, tie to -5 V
AV_{DD}	4	Positive analog supply voltage, tie to +5 V
AGND	5	The ground reference point of all analog circuitry of the device. Tie to 0 V.
DGND	6, 7, 8, 15	Tie to DGND to ensure correct operation.
SDIN	9	Digital input, serial data. Ignored when \overline{CS} is high.
SCLK	10	Digital input, serial bit clock. Ignored when \overline{CS} is high.
CS	11	Digital input. Chip Select (\overline{CS}) signal. Active low. When \overline{CS} is high, SCLK and SDI are ignored. When \overline{CS} is low, data can be transferred into the device.
DGND	12	Ground reference for digital circuitry. Tie to 0 V.
DV_DD	13	Positive digital supply, 1.8 V-5.5 V compatible
CLR	14	Digital input for forcing the output to midscale. Active low. When pin CLR is low during 16 th SCLK following the falling edge of CS, the falling edge of 16 th SCLK sets DAC Latch to midcode, and the DAC output to 0 V. When pin CLR is High, the falling edge of 16th SCLK updates DAC latch with the value of input shift register, and changes DAC output to corresponding level.
DV_DD	16	Tie to DV _{DD} to ensure correct operation.

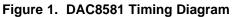
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TIMING REQUIREMENTS⁽¹⁾

	PARAMETER	MIN	MAX	UNIT
t _{SCK}	SCLK period	20		ns
t _{WSCK}	SCLK high or low time	10		ns
t _{Lead}	Delay from falling CS to first rising SCLK	20		ns
t _{TD}	CS High between two active Periods	20		ns
t _{SU}	Data setup time (Input)	5		ns
t _H I	Data hold time (input)	5		ns
t _R	Rise time		30	ns
t _F	Fall time		30	ns
t _{WAIT}	Delay from 16th falling edge of SCLK to \overline{CS} low	100		ns
t _{UPDAC}	Delay from 16th falling edge of SCLK to DAC output	1		μs
	V _{DD} High to CS Low (power-up delay)	100		μs

(1) Assured by design. Not production tested.

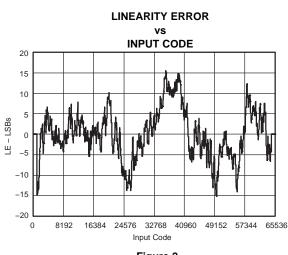




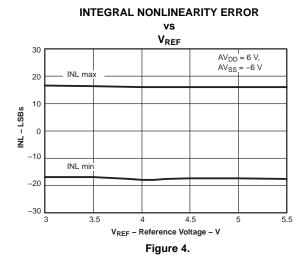


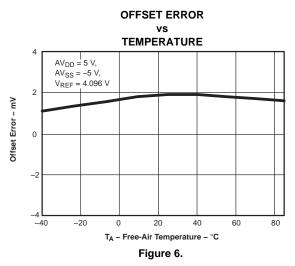
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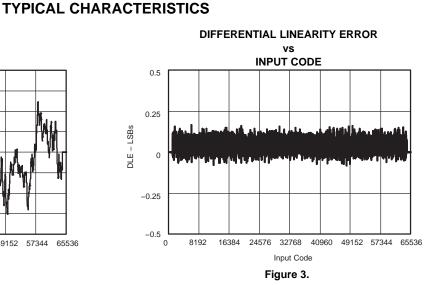
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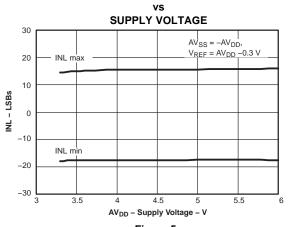




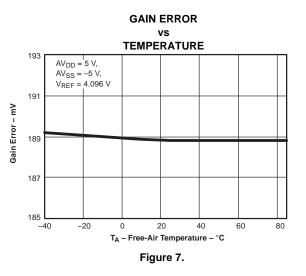




INTEGRAL NONLINEARITY ERROR

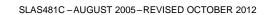


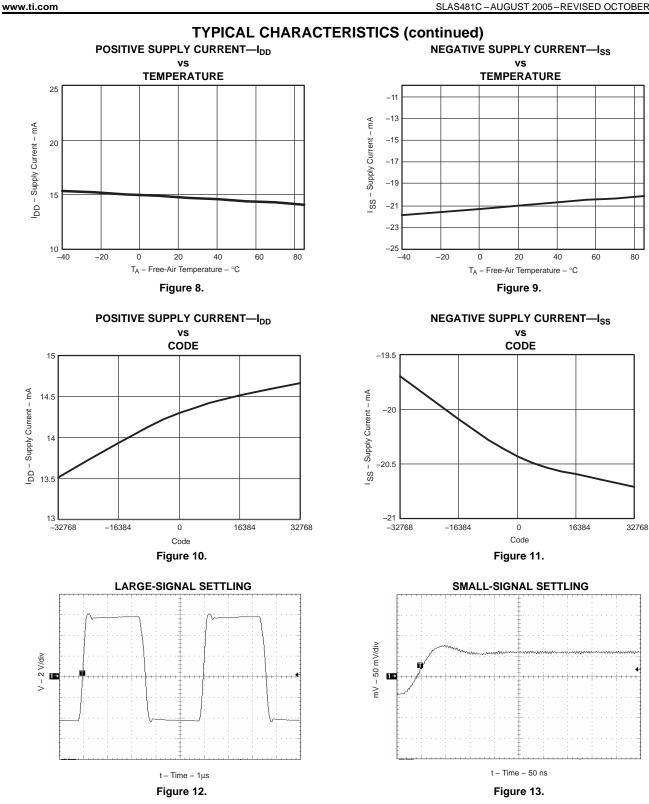




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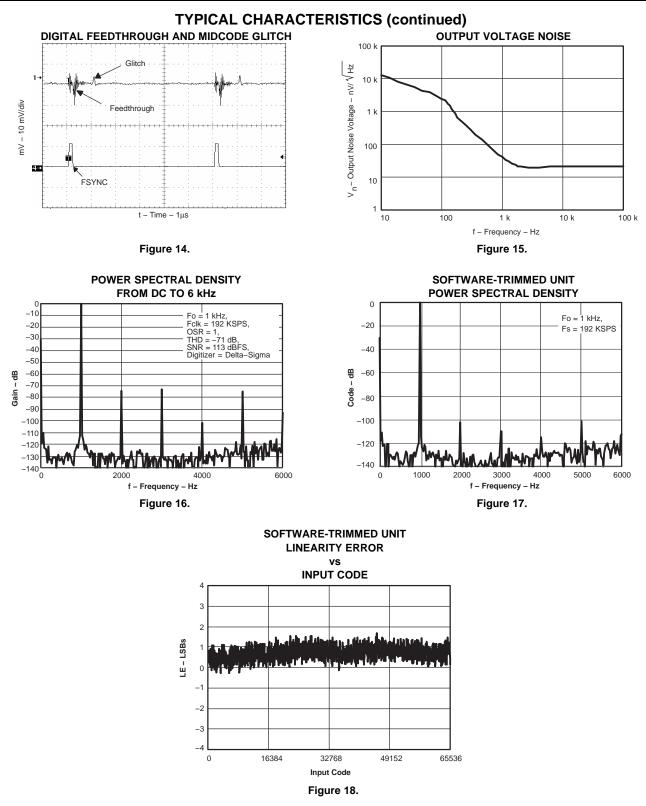






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THEORY OF OPERATION

The DAC8581 uses a proprietary, monotonic, high-speed resistor string architecture. The 16-bit input data are coded in twos complement, MSB-first format and transmitted using a 3-wire serial interface. The serial interface sends the input data to the DAC latch. The digital data are then decoded to select a tap voltage of the resistor string. The resistor string output is sent to a high-performance output amplifier. The output buffer has bipolar (± 5 V) swing capability on a 600- Ω , 200-pF load. The resistor string DAC architecture provides exceptional differential linearity and temperature stability whereas the output buffer provides fast-settling, low-glitch, and exceptionally low idle-channel noise. The DAC8581 settles within 1 µs for large input signals. Exceptionally low glitch (0.5 nV-s) is attainable for small-signal, code-to-code output changes. The resistor string architecture also provides code-independent power consumption and code-independent settling time. The DAC8581 resistor string needs an external reference voltage to set the output voltage range of the DAC. To aid fast settling, V_{REF} input is internally buffered.

Supply Pins

The DAC8581 uses ±5-V analog power supplies (AV_{DD}, AV_{SS}) and a 1.8-V to 5.5-V digital supply (DV_{DD}). Analog and digital ground pins (AGND and DGND) are also provided. For low-noise operation, analog and digital power and ground pins should be separated. Sufficient bypass capacitors, at least 1 μ F, should be placed between AV_{DD} and AV_{SS}, AV_{SS} and DGND, and DV_{DD} and DGND pins. Series inductors are *not* recommended on the supply paths. The digital input pins should not exceed the ground potential during power up. During power up, AGND and DGND are first applied with all digital inputs and the reference input kept at 0 V. Then, AV_{DD}, DV_{DD}, AV_{SS}, and V_{REF} should be applied together. Care should be taken to avoid applying V_{REF} before AV_{DD} and AV_{SS}. All digital pins must be kept at ground potential before power up.

Reference Input Voltage

The reference input pin V_{REF} is typically tied to a +3.3-V, +4.096-V, or +5.0-V external reference. A bypass capacitor (0.1 μ F or less) is recommended, depending on the load-driving capability of the voltage reference. To reduce crosstalk and improve settling time, the V_{REF} pin is internally buffered by a high-performance amplifier. The V_{REF} pin has constant 5-k Ω impedance to AGND. The output range of the DAC8581 is equal to ±V_{REF} voltage. The V_{REF} pin should be powered at the same time, or after the supply pins. REF3133 and REF3140 are recommended to set the DAC8581 output range to ±3.3 V and ±4.096 V, respectively.

Output Voltage

The input data format is in twos-complement format as shown in Table 1. The DAC8581 uses a highperformance, bipolar output buffer capable of driving a 600- Ω , 200-pF load with fast 0.65-µs settling. The buffer has exceptional noise performance (20 nV/ \sqrt{Hz}) and fast slew rate (35 V/µs). The small-signal settling time is under 300 ns, allowing update rates up to 3 MSPS. Loads of 50 Ω or 75 Ω could be driven as long as output current does not exceed ±25 mA continuously. Long cables, up to 1 nF in capacitance, can be driven without the use of external buffers. To aid stability under large capacitive loads (>1 nF), a small series resistor can be used at the output.

	DIGITAL CODE	
DAC OUTPUT	BINARY	HEX
+V _{REF}	01111111111111	7FFF
+V _{REF} /2	01000000000000	4000
0	00000000000000	0000
-V _{REF} /2	10111111111111	BFFF
-V _{REF}	100000000000000	8000

Table 1. Data Format



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Glitch area is low at 0.5 nV-s, with peak glitch amplitude under 10 mV, and the glitch duration under 100 ns. Low glitch is obtained for code-to-code (small signal) changes across the entire transfer function of the device. For large signals, settling characteristics of the reference and output amplifiers are observed in terms of overshoot and undershoot.

Combined with \pm 5-V output range, and extremely good noise performance, the outstanding differential linearity performance of this device becomes significant. That is, each DAC step can be clearly observed at the DAC output, without being corrupted by wideband noise.

SERIAL INTERFACE

The DAC8581 serial interface consists of the serial data input pin SDIN, bit clock pin SCLK, and chip-select pin, \overline{CS} . The serial interface is designed to support the industry standard SPI interface up to 50 MHz. The serial inputs are 1.8-V to 5.5-V logic compatible.

 \overline{CS} operates as an active-low, chip-select signal. The falling edge of \overline{CS} initiates the data transfer. Each rising edge of SCLK following the falling edge of \overline{CS} shifts the SDIN data into a 16-bit shift register, MSB-first. At the 16th rising edge of SCLK, the shift register becomes full and the DAC data updates on the falling edge that follows the 16th rising edge. After the data update, further clocking gets ignored. The sequence restarts at the next falling edge of \overline{CS} . If the \overline{CS} is brought high before the DAC data are updated, the data are ignored. See the timing diagram (Figure 1) for details.

Pin CLR

Pin $\overline{\text{CLR}}$ is implemented to set the DAC output to 0 V. When the $\overline{\text{CS}}$ pin is low during the 16th SCLK cycle following the falling edge of $\overline{\text{CS}}$, the falling edge of the 16th SCLK sets the DAC latch to midcode, and the DAC output to 0 V. If the $\overline{\text{CLR}}$ pin is high during the 16th clock, the falling edge of the 16th clock updates the DAC latch with the input data. Therefore, if the $\overline{\text{CLR}}$ pin is brought back to High from Low during serial communication, the DAC output stays at 0 V until the falling edge of the next 16th clock is received. The $\overline{\text{CLR}}$ pin is active low. $\overline{\text{CLR}}$ low does not affect the serial data transfer. The serial data input doe not get interrupted or lost while the output is set at midscale.

SCLK

This digital input pin is the serial bit-clock. Data are clocked into the device at the rising edge of SCLK.

CS

This digital input pin is the chip-select signal. When \overline{CS} is low, the serial port is enabled and data can be transferred into the device. When \overline{CS} is high, all SCLK and SDIN signals are ignored.

SDIN

This digital input is the serial data input. Serial data are shifted on the rising edge of the SCLK when \overline{CS} is low.



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APPLICATION INFORMATION

IMPROVING DAC8581 LINEARITY USING EXTERNAL CALIBRATION

At output frequencies up to 50 kHz, DAC8581 linearity error and total harmonic distortion are dominated by resistor mismatches in the string. These resistor mismatches are fairly insensitive to temperature and aging effects and also to reference voltage changes. Therefore, it is possible to use a piece-wise linear (PWL) approximation to cancel linearity errors, and the calibration remains effective for different supply and V_{REF} voltages, etc. The cancellation of linearity errors also improves the total harmonic distortion (THD) performance. It is possible to improve the integral linearity errors from ±25 LSB to ±1 LSB and the THD from -70 dB to almost -98 dB (see Figure 17 and Figure 18). The improvements are at the expense of ~2x DNL deterioration, which is not critical for the generation of large-signal waveforms.

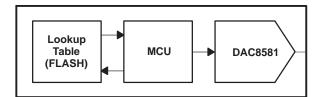


Figure 19. A Simple Printed-Circuit Board Scheme for Calibrated Use of DAC8581

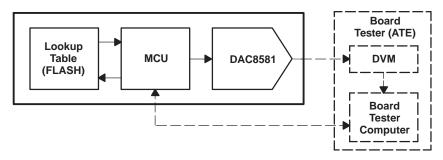


Figure 20. Production Test Setup for a DAC8581 Board With Calibration

The PWL calibration scheme uses a DAC8581 and a microcontroller unit (MCU) with flash memory, on a printedcircuit board as seen in Figure 19. Calibration is done during board test, and the calibration coefficients are stored permanently in flash memory as seen in Figure 20. An automated board tester is assumed to have a precision digital voltmeter (DVM) and a tester computer. The test flow for a 1024-segment, piece-wise linear calibration is as follows:

- 1. Use the tester computer to load software into the MCU to ramp the DAC8581 and:
 - Take a reading at each step after a short wait time
 - Store 65,536 readings in the tester computer volatile memory
- 2. Use the tester computer to:
 - Search the 65,536-point capture data and find the actual DAC8581 codes which would generate ideal DAC outputs for DAC input codes 0, 64, 128, 192,
 - Store these actual codes in the onboard microcontroller's flash memory in a 1025-point array called COEFF[].
- 3. Use the tester computer to program the MCU such that, when the end-user provides new 16-bit input data D0 to the MCU:
 - The 10 MSBs of D0 directly index the array COEFF[].
 - The content of indexed memory of COEFF[] and the content of the next higher memory location are placed in variables I1 and I2.
 - The six LSBs of the user data D0 with two variables I1 and I2 are used for computing Equation 1 (see Figure 21).
 - Instead of D0, I0 is loaded to DAC8581



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(1)

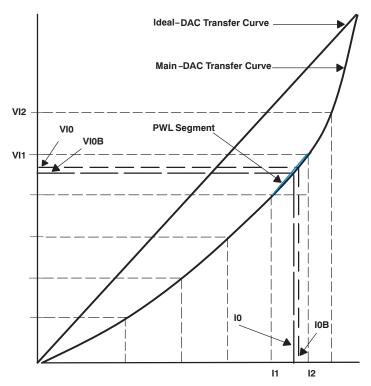


Figure 21. The Geometry Behind the PWL Calibration

$$I0 = \frac{I1 + (I2 - I1)(D0 - VI1)}{VI2 - VI1}$$

Where both x-axis and y-axis are normalized from 0 to 65535, and:

- VI0: Desired ideal DAC voltage corresponding to input code D0.
- VI0B: DAC8581 output voltage, which approximates VI0 after PWL calibration. This is the actual DAC8581 output for input code D0 after PWL calibration.
 - I0: DAC8581 code generating VI0B, an approximation to the desired voltage VI0. This is actual code loaded into DAC latch for input code D0, after PWL calibration.
 - I0B: DAC8581 code, which generates output VI0. This code is approximated by the N-segment PWL calibration.
 - I1: Contents of memory COEFF[], addressed by the 10 MSBs of user input code D0.
 - 12: Contents of the next memory location in COEFF[].
 - VI1: DAC8581 output voltage corresponding to code I1. Notice that (D0–VI1) is nothing but the six LSBs of the input code D0, given that the y-axis is normalized from 0 to 65,536.
 - VI2: DAC8581 output voltage corresponding to code I2. Notice that (VI2–VI1) is always equal to number 64, given that the y-axis is normalized from 0 to 65,536. Division becomes a 6-bit arithmetic right shift.

Other similar PWL calibration implementations exist. This particular algorithm does not need digital division, and it does not accumulate measurement errors at each segment.



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REVISION HISTORY

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

CI	hanges from Revision A (August, 2005) to Revision B Pa	age
•	Updated document format to current stylistic standards	1
•	Deleted lead temperature specifications from Absolute Maximum Ratings table	2
•	Deleted footnote 1 from Electrical Characteristics table	3
•	Revised test conditions for voltage output specification	3

Changes from Revision B (December 2009) to Revision C

•	Changed "rail-to-rail" to "bipolar"	 1
•	Changed "rail-to-rail" to "bipolar"	 9



PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow		(6)
						(4)	(5)		
DAC8581IPW	NRND	Production	TSSOP (PW) 16	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	D8581I
DAC8581IPW.B	NRND	Production	TSSOP (PW) 16	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	D8581I
DAC8581IPWR	NRND	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	D8581I
DAC8581IPWR.B	NRND	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	D8581I

⁽¹⁾ **Status:** For more details on status, see our product life cycle.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All	dimensions	are	nominal	

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DAC8581IPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



PACKAGE MATERIALS INFORMATION

23-May-2025



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
DAC8581IPWR	TSSOP	PW	16	2000	350.0	350.0	43.0

TEXAS INSTRUMENTS

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TUBE



- B - Alignment groove width

*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
DAC8581IPW	PW	TSSOP	16	90	530	10.2	3600	3.5
DAC8581IPW.B	PW	TSSOP	16	90	530	10.2	3600	3.5

PW0016A



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.

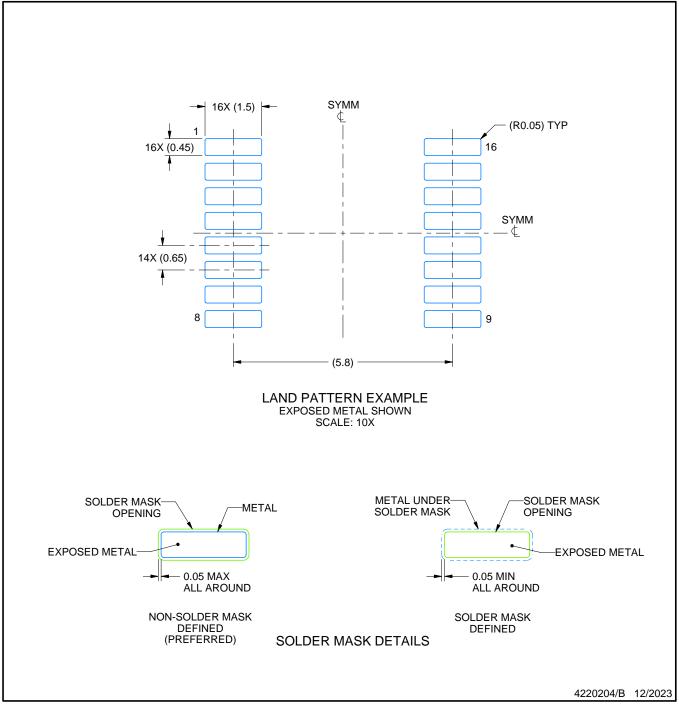


PW0016A

EXAMPLE BOARD LAYOUT

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

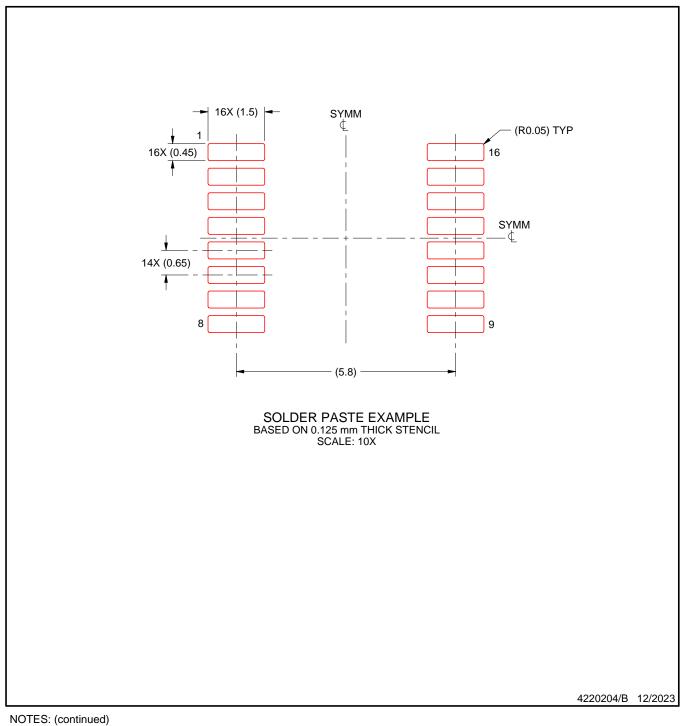


PW0016A

EXAMPLE STENCIL DESIGN

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE





^{8.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

^{9.} Board assembly site may have different recommendations for stencil design.

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